

Intuitive approach to the unified theory of spin relaxation

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Spin relaxation is conventionally discussed using two different approaches for materials with and without inversion symmetry. The former is known as the Elliott-Yafet (EY) theory and for the latter the D'yakonov-Perel' (DP) theory applies. We discuss herein a simple and intuitive approach to demonstrate that the two seemingly disparate mechanisms are closely related. A compelling analogy between the respective Hamiltonians is presented, and that the usual derivation of spin-relaxation times, in the respective frameworks of the two theories, can be performed. The result also allows us to obtain less canonical spin-relaxation regimes, i.e. the generalization of the EY when the material has a large quasiparticle broadening, and the DP mechanism in ultrapure semiconductors. The method also allows a practical and intuitive numerical implementation of the spin-relaxation calculation, which is demonstrated for MgB₂, which has anomalous spin-relaxation properties.

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I. INTRODUCTION

The emerging possibility to use electron spins as information carriers and storage units (a field known as spintronics [1–3]) calls for the development of the fundamental description of spin-diffusion and spin-relaxation phenomena. The conventional theory of spin relaxation in materials is based on the so-called Elliott-Yafet (EY) theory [4,5] and the D'yakonov-Perel' (DP) mechanisms [6,7] depending on whether the material possesses or not a spatial inversion symmetry, respectively. Most elemental metals are examples of a retained inversion symmetry but zinc-blende semiconductors (e.g., GaAs), even though they have a cubic crystal structure, are examples of a broken spatial inversion. The two theories are also based on different approaches: the EY theory studies momentum scattering induced spin-flip events, whereas the DP theory considers the electron-spin precession around built-in magnetic fields, which are due to spin-orbit coupling (SOC). Common in both theories is that SOC is the primary reason of the spin flip or spin rotation but it is small compared to typical orbital interactions.

The spin-relaxation time, τ_s , depends on the momentum relaxation time, τ , however with the opposite dependence: $\tau_s \propto \tau$ in the EY theory, whereas $\tau_s \propto 1/\tau$ in the DP theory. The different phenomenology is used as a benchmark to classify spin relaxation in a novel material (e.g., graphene [8–11]) into one or the other mechanisms.

Yafet realized in his seminal paper that extension of the conventional EY theory may be required [12]. He predicted properly that band degeneracies lead to anomalous spin relaxation, such as that observed in aluminium [13], which was explained by the so-called spin hot-spot model [14,15]. The next hint, that the spin-relaxation theory is yet incomplete and that analogous behaviors of the EY and DP theories exist, came from experiment. Electron-spin-relaxation studies

were performed on materials with spatial inversion symmetry and a short momentum relaxation time, e.g., MgB_2 [16], a material which displays both phenomenologies: $\tau_s \propto \tau$ for temperatures below 150 K and $\tau_s \propto 1/\tau$ for T > 400 K and an intermediate range in between. Another material with a short τ and retained inversion symmetry is $\mathrm{Rb}_3\mathrm{C}_{60}$ [17] which displays $\tau_s \propto 1/\tau$ in the whole temperature range. The experiments in both materials were successfully explained by the so-called generalized EY theory (GEY) in Refs. [18,19]. The conventional DP mechanism is also known to require extensions which result in an EY-like phenomenology in inversion symmetry-breaking semiconductors with a very long τ , in high magnetic fields [2,7,20], and in the presence of a large spin-orbit coupling [21–27].

The unification of the two theories was first attempted in Ref. [28]: it was shown that a common quantum kinetic description based approach, and considering different SOC terms for EY-like and DP-like mechanisms, allows us to obtain both the EY and the DP theories in a single and compact expression. However, this involved approach appears to be characteristically different from the mathematics of the original EY and DP theories, therefore the intimate link between the two theories remains hidden.

This paper is intended to shed light on this link and we show that formally an analogy between the DP and EY mechanisms can be found. This allows us to derive the results of both mechanisms in the framework of the other. We explicitly show this for the EY and GEY mechanisms: the results of spin relaxation for these cases are derived from a DP-like approach using the quasiparticle picture combined with internal, spin-orbit coupling related magnetic fields. This enables a unified treatment of spin relaxation and it allows for a readily programmable tool to study spin relaxation in metals and semiconductors. Our approach also provides an alternative physical description for the EY mechanism: motional narrowing instead of the usual Fermi's "golden rule" description.

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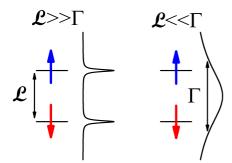


FIG. 1. Level scheme and quasiparticle broadening depicted for a material with broken inversion symmetry. Left: $\mathcal{L} \gg \Gamma$. Right: Level scheme when $\mathcal{L} \ll \Gamma$. The latter is the conventional DP model.

II. CONVENTIONAL DESCRIPTIONS OF SPIN RELAXATION

A. D'yakonov-Perel' theory

The D'yakonov-Perel' mechanism describes the spin relaxation in an inversion-breaking material, which is realized in, e.g., zinc-blende (like GaAs) semiconductors. The lack of inversion symmetry gives rise to built-in, SOC related k-vector dependent effective magnetic fields, B_k , around which the electron spins precess between two momentum scattering events. The corresponding Larmor frequencies of the precession are $\Omega_k = \gamma B_k$, where $\gamma \approx 2\pi \times 28 \, \mathrm{GHz/T}$ is the electron gyromagnetic ratio.

The corresponding band structure is shown in Fig. 1 for two cases: when momentum scattering is small or large compared to the strength of the spin-orbit interaction. We also introduced in the figure the spin-orbit coupling terms, \mathcal{L}_k , which correspond to the following Hamiltonian:

$$H_{\rm DP} = \oint_{\downarrow} \begin{bmatrix} 0 & \mathcal{L}_k \\ \mathcal{L}_k^* & 0 \end{bmatrix}. \tag{1}$$

The Hamiltonian is based on spin eigenstates. The connection between the effective magnetic field and the spin Hamiltonian is $\hbar |\Omega_k| = 2\mathcal{L}_k$. In the following, we denote by \mathcal{L} a Fermisurface average, $\langle . \rangle_{FS}$, of the SOC term: $\mathcal{L} = \sqrt{\langle \mathcal{L}_k^2 \rangle_{FS}}$. We also introduce the momentum scattering rate $\Gamma = \hbar/\tau$ and we shall also use the analogous spin-relaxation rate as $\Gamma_s = \hbar/\tau_s$.

The canonical D'yakonov-Perel' theory applies when the momentum relaxation is rapid, $\mathcal{L} \ll \Gamma$, i.e., the electron spins rotate by a small angle $\delta \phi \approx \Omega \tau$ between two consecutive momentum scattering events. The spin relaxation in this case reads [6,7]

$$\Gamma_{\rm s} = \alpha \frac{\mathcal{L}^2}{\Gamma},$$
(2)

i.e., the $\Gamma_s \propto \Gamma^{-1}$ is realized. Herein, α is a band-structure dependent constant near unity. The D'yakonov-Perel' mechanism is essentially a motional narrowing description, i.e., the otherwise broad distribution of built-in precession frequencies are averaged out.

The other limit, i.e., $\mathcal{L} \gg \Gamma$, is realized in ultrapure semiconductors and it was observed experimentally in Refs. [25,26] with the corresponding theory worked out in Refs. [23,29,30].

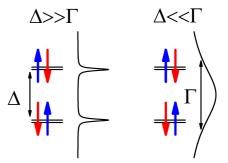


FIG. 2. Level scheme and momentum scattering rate depicted for a material with retained inversional symmetry. Note that the spin states are degenerate. Left: $\Delta \gg \Gamma$. Right: Level scheme when $\Delta \ll \Gamma$. The former is the conventional EY model, while the latter is the so-called generalized EY model, worked out in Refs. [18,19].

We recently studied this problem using a Monte Carlo approach [31] and identified two regimes: if the spread in the Larmor frequencies, $\Delta\Omega$, is smaller than Γ/\hbar , the spin relaxation is oscillatory with a single exponent:

$$\Gamma_{\rm s} = \alpha \Gamma.$$
 (3)

However, when $\Delta\Omega\gg\Gamma/\hbar$, the spread in the built-in magnetic fields is larger than Γ and there is an initial dephasing on the time scale of $1/\Delta\Omega$ that is followed by an exponential-like decay.

B. Elliott-Yafet model

Our effective Elliott-Yafet model includes four bands, two of which remain pairwise degenerate even in the presence of SOC. This is the direct consequence of the Kramers theorem when inversion symmetry is retained, however an external magnetic field would break the time-reversal symmetry and lift the degeneracy. The states in different bands are connected by SOC and the resulting effective Hamiltonian reads

$$H_{\text{EY}} = \begin{bmatrix} 1 \uparrow & 1 \downarrow & 2 \uparrow & 2 \downarrow \\ 1 \uparrow & 0 & 0 & 0 & L_k \\ 1 \downarrow & 0 & 0 & L_k^* & 0 \\ 0 & L_k & \Delta_k & 0 \\ 2 \downarrow & L_k^* & 0 & 0 & \Delta_k \end{bmatrix}, \tag{4}$$

where 1 and 2 are orbital states, L_k is the spin-orbit matrix element, and Δ_k is the band gap. In principle, there could be matrix elements between $1\uparrow$ and $2\uparrow$ but these would not contribute to spin relaxation [28] in leading order and are thus omitted. Similar to the introduction of \mathcal{L} , we define the following average values: $L = \sqrt{\langle L_k^2 \rangle_{\text{FS}}}$ and $\Delta = \sqrt{\langle \Delta_k^2 \rangle_{\text{FS}}}$. In Fig. 2, we show the level scheme for the case when

In Fig. 2, we show the level scheme for the case when inversion symmetry is retained. The conventional EY model assumes the hierarchy $L \ll \Gamma \ll \Delta$, therefore the states are weak admixtures of the original pure spin-up and -down states:

$$|\widetilde{1\uparrow}\rangle_{k} = |1\uparrow\rangle_{k} + \frac{L_{k}}{\Delta_{k}}|2\downarrow\rangle_{k},$$

$$|\widetilde{1\downarrow}\rangle_{k} = |1\downarrow\rangle_{k} - \frac{L_{k}^{*}}{\Delta_{k}}|2\uparrow\rangle_{k}$$
(5)

and correspondingly for the other two states.

Elliott considered the probability of a spin flip during momentum scattering between the $|\widetilde{1\uparrow}\rangle_k$ and $|\widetilde{1\downarrow}\rangle_k$ eigenstates and showed using first-order time-dependent perturbation theory that the transition probabilities of the spin flip, $W_{k\widetilde{\uparrow}\to k\widetilde{\downarrow}}$, and momentum scattering, $W_{k\to k'}$, processes are related by

$$W_{k\widetilde{\uparrow}\to k'\widetilde{\downarrow}} = \alpha \frac{L_k^2}{\Delta_k^2} W_{k\to k'},\tag{6}$$

where α is again a band-structure dependent constant near unity. This yields the well-known EY expression

$$\Gamma_{\rm s} = \left\langle \frac{L_k^2}{\Delta_k^2} \right\rangle_{\rm FS} \cdot \Gamma \approx \alpha \frac{L^2}{\Delta^2} \Gamma.$$
 (7)

The so-called generalized EY scenario is depicted in the right panel of Fig. 2 with the corresponding hierarchy of the parameters: $L \ll \Delta \ll \Gamma$. This situation is realized in materials where there is a fourfold band degeneracy (such as, e.g., in graphene at the Dirac point) or a near band degeneracy the splitting of which is smaller than the momentum scattering rate. The latter situation is encountered in MgB2 which is a relatively high-temperature superconductor ($T_c = 40 \,\mathrm{K}$), thus it has a strong electron-phonon coupling (i.e., a large Γ) and the conduction band has a near band degeneracy due to the two boron atoms in the unit cell. The other known examples are alkali atom doped fullerides, K₃C₆₀ and Rb₃C₆₀, which also show a large electron-phonon coupling, and a conduction band which is derived from the threefold degenerate C₆₀ molecular orbitals, and the degeneracy lifting is moderate compared to Γ .

Clearly, for such a case the lowest-order time-dependent perturbation theory is not applicable. A many-body based approach, which is essentially infinite order in momentum scattering (but remains lowest, i.e., second order in the SOC), was performed in Refs. [18,19]. It gave the remarkably simple result

$$\Gamma_{\rm s} = \alpha \frac{L^2}{\Lambda^2 + \Gamma^2} \Gamma. \tag{8}$$

Clearly, the GEY regime gives $\Gamma_s \propto \frac{L^2}{\Gamma}$, which looks surprisingly similar to the DP result of Eq. (2). This immediately leads to questions as to whether the agreement is only accidental or there is something behind the agreement, i.e., that a large Γ inevitably corresponds to a breaking of the lattice symmetry (both phonons and impurities lead to this).

Another point awaiting clarification is whether a simpler, less involved derivation of the GEY regime is possible without the many-body considerations.

III. ANALOGY OF THE EY AND DP HAMILTONIANS

We first demonstrate how the EY Hamiltonian can be related to the DP problem. We consider a transformation of the spin states in the Elliott-Yafet Hamiltonian in Eq. (4) as follows:

$$|A \uparrow\rangle = |1 \uparrow\rangle,$$

$$|A \downarrow\rangle = |2 \downarrow\rangle,$$

$$|B \uparrow\rangle = |2 \uparrow\rangle,$$

$$|B \downarrow\rangle = |1 \downarrow\rangle.$$
(9)

The Hamiltonian for these states reads

$$H'_{EY} = \begin{pmatrix} A \uparrow & A \downarrow & B \uparrow & B \downarrow \\ A \uparrow & 0 & L_k & 0 & 0 \\ A \downarrow & L_k^* & \Delta_k & 0 & 0 \\ B \uparrow & 0 & 0 & \Delta_k & L_k \\ 0 & 0 & L_k^* & 0 \end{pmatrix}.$$
(10)

This procedure is equivalent to a unitary transformation of the EY Hamiltonian with the following matrix:

$$H'_{\rm EY} = P^{\dagger} H_{\rm EY} P,$$

$$P = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & 0 & 0 & 1 \\ 0 & 0 & 1 & 0 \\ 0 & 1 & 0 & 0 \end{bmatrix}.$$
(11)

In the original basis we had pure spin states, however in the new basis the usual Pauli matrices need to be transformed, too. Therefore we rather refer to the new basis states as pseudospin states.

This Hamiltonian decouples to the direct sum of two single pseudospin Hamiltonians. This is the consequence of the simple structure of the original Hamiltonian in Eq. (4) as it did not contain terms which would join, e.g., $A \uparrow$ with $B \uparrow$. It is important to note that momentum scattering does not induce transitions between the A and B states in this model Hamiltonian either, as momentum scattering alone is unable to flip an electron spin, except for a magnetic scatterer which is not involved in the EY theory. This means that if an electron is born to be of the A type it remains so throughout in the spin-relaxation problem. We discuss in the Appendix that the procedure can be performed in the presence of terms like between the $1 \uparrow$ and $2 \uparrow$ states as well but the result lacks compactness.

The 2×2 blocks in Eq. (10) show a remarkable similarity to the DP Hamiltonian in Eq. (1) except for the presence of the Δ term. We note that the L_k terms are the SOC matrix elements for a material with retained inversion symmetry. As we show below, this allows us to "formally" treat the EY spin-relaxation mechanism with the usual DP-like approach, i.e., by the evolution of the pseudospin ensemble upon internal built-in magnetic fields. In the end of the pseudospin evolution, the result can be obtained for the real spin by transforming it back.

We then discuss how the DP Hamiltonian can be traced back to the EY problem. We consider the DP Hamiltonian in Eq. (1), introduce an external magnetic field with Zeeman energy Δ_Z , and amend the system with a pair of virtual electron spin states, which have the same SOC but interact with the external magnetic field with opposite sign as compared to the physical electron states. This gives

$$H'_{\rm DP} = \begin{bmatrix} 0 & \mathcal{L}_k & 0 & 0\\ \mathcal{L}_k^* & \Delta_{Z,k} & 0 & 0\\ 0 & 0 & \Delta_{Z,k} & \mathcal{L}_k\\ 0 & 0 & \mathcal{L}_k^* & 0 \end{bmatrix}. \tag{12}$$

We also shifted the zero of the energy as the Zeeman term would normally introduce a $\pm \Delta_Z/2$ shift of the levels. We retained the k dependence of the Zeeman term as the g factor can be k dependent. Clearly, a similar transformation

of the states, identical to that presented above, yields the EY Hamiltonian for the DP problem. We emphasize that the \mathcal{L}_k terms originate from an SOC due to inversion symmetry breaking, still it can be rewritten as if it was valid for a system with retained inversion.

Given that the additional virtual electron states are not connected with the true physical electrons, we believe that the usual treatment of spin relaxation in inversionally symmetric materials, i.e., first-order perturbation theory for the conventional EY and many-body approach for the GEY, can be performed for these states, too.

IV. DERIVING THE EY AND GEY RESULTS USING A DP CONSIDERATION

The Hamiltonian in Eq. (10) describes independent time evolution for the A and B electrons and their pseudospins, which can be described by Larmor precession with the following angular frequency vectors:

$$\mathbf{\Omega}_{A,k} = \frac{2}{\hbar} \begin{bmatrix} -\text{Re}[L_k] \\ \text{Im}[L_k] \\ \Delta_k/2 \end{bmatrix}, \quad \mathbf{\Omega}_{B,k} = \frac{2}{\hbar} \begin{bmatrix} -\text{Re}[L_k] \\ \text{Im}[L_k] \\ -\Delta_k/2 \end{bmatrix}. \quad (13)$$

The presence of an effective model which contains a twopseudospin-level state only with an internal SOC derived magnetic field is a surprisingly analogous situation to the DP description of spin relaxation in semiconductors. We emphasize that the original system has inversion symmetry but at least formally it can be rewritten to look like the DP Hamiltonian in Eq. (1). It is therefore tempting to employ the DP framework to derive the EY and GEY results. This means that one follows the time evolution of a pseudospin ensemble upon Larmor precessions according to Eq. (13) between two momentum scattering events. We note that the basis change from $|1 \uparrow\rangle$... to $|A \uparrow\rangle$... affects the x and y rotations of the original spin, however the transformation leaves the s_z Pauli matrix invariant. In the models of spin relaxation, the z or a quantization axis is chosen along which a nonequilibrium spin population is induced either by magnetic resonance or by spin injection. This means that we are following the time decay of the z component, which is identical for both the usual spin and the pseudospin.

The spin relaxation under the action of built-in SOC related fields and an additional magnetic field along the z axis was worked out analytically in Ref. [32] [Eq. (IV.36)]:

$$\Gamma_{\rm s} = \left(\overline{\Omega_x^2} + \overline{\Omega_y^2}\right) \frac{\tau_c}{\Omega_0^2 \tau_c^2 + 1}.$$
 (14)

Herein, Ω_x and Ω_y denote the Larmor (angular) frequencies due to SOC fields along the x and y axes, respectively, which in our notation are identified with $\hbar\Omega_x = -2\text{Re}[L_k]$ and $\hbar\Omega_y = 2\text{Im}[L_k]$. τ_c is the correlation time of the electron scattering, which is identified with the usual momentum scattering in our case, and Ω_0 is the Larmor angular frequency due to the magnetic field along the z axis. In the EY model, Δ_k plays the role of the Zeeman splitting, thus the assignment is $\hbar\Omega_0 = \Delta$. Clearly, Eq. (14), together with the angular frequencies given in Eq. (13), can be rewritten as

$$\Gamma_{\rm s} = \frac{4L^2}{\Delta^2 + \Gamma^2} \Gamma. \tag{15}$$

This formula is identical to Eq. (8), which was originally derived for the generalized EY mechanism using a quantum kinetic approach.

Let us briefly reflect on the above derivation. We essentially start with pure spin states (Pauli eigenstates) and consider both disorder and spin-orbit coupling as perturbations. The spin-orbit coupling leads to a coherent-spin dynamics between two nondegenerate levels, separated by Δ_k . If the scattering is faster than the spin precession, we are in the motional narrowing regime and the EY mechanism and the electron state does not become fully "dressed" by SOC. In contrast, if the coherent dynamics is long enough, the electron states fully explore the Hilbert states of the available bands and the spin relaxation approaches the EY formula. However, the above does not hold in the spin hot-spot regime [14,15] where $\Delta_k \leq L_k$. In this regime the spin-flip probability can be as large as the spin-conserving one, and perturbation theory within the Markov approximation, which leads to the formula Eq. (15), is not valid.

V. SPIN-RELAXATION RATE CALCULATION FOR A REALISTIC CASE

The above presented unified treatment of the EY-GEY and DP spin-relaxation regimes not only represents a simple and intuitive description but it allows for a practical and easily implemented calculation of spin-relaxation times (or rates). The original EY theory and in particular the GEY regime are difficult to implement in practice to yield spin-relaxation rate values. However, the treatment of the DP scenario is more intuitive: it considers the evolution of a spin ensemble under the action of built-in SOC fields. We demonstrate this for MgB₂: in this material, a crossover from the conventional EY to the GEY regime was observed experimentally using electron-spin-resonance measurements [16,18]. At low T, the conventional EY regime dominates as the electron-spinresonance linewidth and resistivity are proportional, thus $\Gamma_{\rm s} \propto \Gamma$. However, above about 200 K, it crosses over to the GEY regime as the quasiparticle broadening, Γ , becomes comparable to the band-band separation of boron σ bands in the vicinity of the Fermi surface. The large Γ is the result of a large electron-phonon coupling, which is also the cause of the superconducting transition at 40 K. The presence of nearly degenerate boron σ bands on the Fermi surface is due to the presence of two boron basis atoms.

We show the experimental and calculated spin-relaxation rates, Γ_s , in Fig. 3. The experimental data are from Ref. [18] and are obtained after subtracting the spin-relaxation rate contribution from the boron π bands. It is described in Ref. [18] that the latter obeys the conventional EY mechanism as the boron π bands are separated from each other with a large gap (2 eV). In contrast, the separation of the boron σ bands is as low as ~ 0.2 eV.

To calculate the spin-relaxation rate in the framework of the above description, we consider the EY Hamiltonian of Eq. (4) with an isotropic SOC (i.e., the off-diagonal 2×2 matrix has diagonal terms, too). It is transformed to a DP-like Hamiltonian according to the procedure described above (the diagonal terms of the off-diagonal 2×2 matrix are eliminated according to the Appendix). The rest of the calculation proceeds according to the Monte Carlo simulation procedure of a DP problem, which

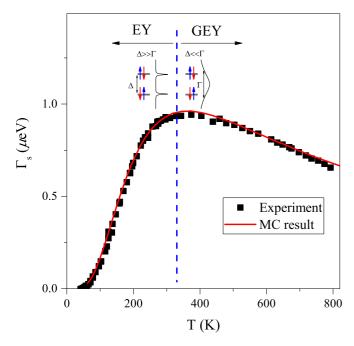


FIG. 3. Experimental (symbols) and Monte Carlo based (solid curve) spin-relaxation rate Γ_s in MgB₂. Note that the experimental data contain the contribution from the boron σ bands only; as described in Ref. [18], the contribution from the π bands remains explicable by the conventional EY theory and it is thus subtracted. The level scheme and the identification of the EY and GEY regimes are also depicted. Note that the two regimes cross over smoothly as a function of temperature and the vertical dashed line is intended as a guide only.

is discussed in depth in Ref. [31] and is briefly summarized herein.

The Monte Carlo method considers an electron ensemble with spin polarized along the z axis at t = 0. Each electron has a different (random) k value and they experience a different built-in Larmor precession. The latter vectors are obtained according to the above-described transformation procedure. Momentum scattering is approximated by giving each electron a new random k value after a time τ' elapses, where τ' is a statistical variable with a Poisson distribution and a mean value of the momentum relaxation time, τ . The decay of the electronspin ensemble magnetization along the z axis is monitored as a function of time and is fitted with a single exponential. The exponent yields directly the spin-relaxation time, τ_s . The variation of this parameter, or its rate $\Gamma_s = \hbar/\tau_s$, is followed as a function of Γ . Appendix shows Γ_s in units of L^2/Δ as a function of Γ (in units of Δ) for a low value of the spin-orbit coupling ($L=0.1\Delta$). In the low L limit, this $\Gamma_{\rm s}(\Gamma)$ function is universal and can be well fitted by $\Gamma_s = \frac{2}{3} \frac{\Gamma}{1+\Gamma^2}$. This is exactly the generalized EY result of Eq. (8) which was first deduced in Ref. [18] and is obtained herein numerically.

The final result, which is shown in Fig. 3, is obtained by presenting the data as a function of temperature using the $T(\Gamma)$ relation from the Bloch-Grünneisen function with a Debye temperature of 535 K and also by scaling the data with the already known $\Delta=194\,\mathrm{meV}$ [18] and $L=1.7\,\mathrm{meV}$.

We observe an excellent agreement between the experiment and the spin-relaxation rate which is obtained from the Monte Carlo simulation. This also means that the spin-relaxation rate in MgB₂ can be appropriately described by a single band-band separation value and also by an isotropic SOC model. We emphasize that with this demonstration we traced back a spin-relaxation problem in an inversionally symmetric strongly correlated metal to the methodology which was developed for an inversionally symmetry-breaking material.

VI. SUMMARY

In summary, we presented the connection between the Elliott-Yafet and D'yakonov-Perel' theories of spin relaxation. We showed that a compelling analogy can be realized between the two mechanisms concerning the level structure and the respective model Hamiltonians. This allows an intuitive, albeit not rigorous derivation of both mechanisms based on the framework of the other. We showed recently that the DP-like treatment is readily programmable using a Monte Carlo method [31]. This means that the otherwise involved quantum-mechanical approach of the EY theory, and in particular its extension to the case of strong electron phonon coupling (the so-called generalized EY theory, GEY), can be also treated at a Monte Carlo level. This is explicitly demonstrated for MgB₂, where the EY to GEY crossover is observed and is reproduced numerically. We add that the presented numerical tools could be also extended to study, e.g., SOC induced spin-dephasing mechanisms, such as those described by Wu and Ning in Refs. [33,34].

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APPENDIX A: BLOCK DIAGONALIZATION OF THE GENERAL FOUR-BAND ELLIOTT-YAFET HAMILTONIAN

The most general form of a four-band Hamiltonian that is symmetric to inversion is

$$H_{\text{EY}} = \begin{bmatrix} 1 \uparrow & 1 \downarrow & 2 \uparrow & 2 \downarrow \\ 1 \uparrow & 0 & 0 & L_{2,k} & L_{1,k} \\ 0 & 0 & L_{1,k}^* & -L_{2,k} \\ L_{2,k} & L_{1,k} & \Delta_k & 0 \\ L_{1,k}^* & -L_{2,k} & 0 & \Delta_k \end{bmatrix}, \quad (A1)$$

where $L_{2,k}$ is real. After transforming the states similarly to the main text, we get a Hamiltonian that is not completely block diagonalized:

$$H'_{\text{EY}} = \begin{bmatrix} A \uparrow & A \downarrow & B \uparrow & B \downarrow \\ A \uparrow & 0 & L_{1,k} & L_{2,k} & 0 \\ L_{1,k}^* & \Delta_k & 0 & -L_{2,k} \\ L_{2,k} & 0 & \Delta_k & L_{1,k} \\ 0 & -L_{2,k} & L_{1,k}^* & 0 \end{bmatrix}.$$
(A2)

We can eliminate the $\pm L_{2,k}$ matrix elements by a twodimensional rotation between the kinetic states with a unitary operation which is very similar to the one presented in the main text:

$$|A'\rangle = a|A\rangle - b|B\rangle,$$

$$|B'\rangle = b|A\rangle + a|B\rangle,$$

$$a^{2} + b^{2} = 1, \quad a,b \in R.$$
(A3)

This can also be written as a unitary transformation matrix:

$$H_{\text{EY}}'' = R^{\dagger} H_{\text{EY}}' R,$$

$$R = \begin{bmatrix} a & 0 & b & 0 \\ 0 & a & 0 & b \\ -b & 0 & a & 0 \\ 0 & -b & 0 & a \end{bmatrix}.$$
(A4)

The two subsequent transformations can be reduced to a single unitary transformation:

$$H_{\rm EY,transformed} = U^{\dagger} H_{\rm EY} U$$
,

$$U = PR = \begin{bmatrix} a & 0 & b & 0 \\ 0 & -b & 0 & a \\ -b & 0 & a & 0 \\ 0 & a & 0 & b \end{bmatrix}.$$
 (A5)

With appropriate a and b values, the off-diagonal blocks can be completely canceled out:

$$\Delta'_{k} = \sqrt{\Delta_{k}^{2} + 4L_{2,k}^{2}},$$

$$a_{k} = \sqrt{\frac{\Delta'_{k} + \Delta_{k}}{2\Delta'_{k}}},$$

$$b_{k} = \operatorname{sign}(L_{2,k})\sqrt{\frac{\Delta'_{k} - \Delta_{k}}{2\Delta'_{k}}}.$$
(A6)

After applying the transformation we get the following Hamiltonian:

$$H_{\text{EY,transformed}} = \begin{pmatrix} A' \uparrow & A' \downarrow & B' \uparrow & B' \downarrow \\ A' \uparrow \begin{bmatrix} 1/2(\Delta_k - \Delta'_k) & L_{1,k} & 0 & 0 \\ A' \downarrow & 1/2(\Delta_k + \Delta'_k) & 0 & 0 \\ B' \uparrow & 0 & 0 & 1/2(\Delta_k - \Delta'_k) & L_{1,k} \\ 0 & 0 & L_{1,k}^* & 1/2(\Delta_k + \Delta'_k) \end{bmatrix}. \tag{A7}$$

The resulting Hamiltonian can be treated similarly to Eq. (10), the only difference being that the instances of Δ_k have to be replaced with Δ'_k in the effective magnetic fields.

APPENDIX B: ALTERNATIVE DERIVATION OF THE EY AND GEY RESULTS USING A DP CONSIDERATION

We derived in the main text that the EY model can be considered as being under the action of built-in SOC related magnetic fields and a much larger, band-gap related Zeeman field. This allows us to provide the schematics of spin relaxation for the EY and GEY regimes with a simple consideration.

The situation for the conventional EY is depicted in Fig. 4. We consider a pseudospin ensemble with different k vectors at t = 0 and pseudospins polarized along the z axis, i.e., $s_z(t = 0) = s_0$. The Larmor precession vectors are such [according to Eq. (13)] that these describe a rotation nominally

around the z axis (this does not contribute to pseudospin decay) with some spread in the vector directions in the x-y plane. The latter components are much smaller as $L_k \ll \Delta_k$. The spread in the Larmor precession vector directions will cause a dephasing of the pseudospin polarization. However, a sizable z component remains and a geometric consideration shows it to be $s_{\text{dephased}} = s_0 \frac{\Delta^2}{L^2 + \Delta^2}$. The pseudospin ensemble retains this polarization until a consecutive momentum scattering randomizes the k vectors and the dephasing restarts. This means that per momentum scattering the pseudospin polarization decay is $\frac{L^2}{L^2 + \Delta^2} \approx \frac{L^2}{\Delta^2}$. As mentioned above, the z component of the pseudospin decays together with the usual spin.

It is interesting to note that the initial drop of the ensemble magnetization to $\frac{\Delta^2}{L^2+\Delta^2}$ is the same as what the spin system experiences in the quantum-mechanical description when the SOC is switched on from zero to a finite value: then, the spin-up and -down admixtures lower the spin value according to the wave functions in Eq. (5).

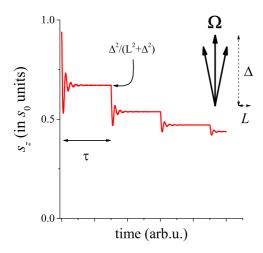


FIG. 4. Schematics of the time evolution of the s_z component of the pseudospin ensemble for the usual EY scenario when described in the DP framework. Note a rapid dephasing to an equilibrium value until the next momentum scattering occurs for the electron ensemble. The inset shows schematically the Larmor vector distribution for this case. The spin polarization tends to zero for long times.

To obtain the spin-relaxation time, we consider the time dependence of the spin ensemble magnetization in the following. After a time τ the value of s_z reads

$$s_z(t+\tau) \approx \frac{\Delta^2}{L^2 + \Delta^2} s_z(t).$$
 (B1)

The reduction of s_z equals $\Delta s_z = -\frac{L^2}{L^2 + \Delta^2} s_z(t)$. The finite difference, $\Delta s_z \approx \frac{ds_z}{dt} \tau$, yields the differential equation for $s_z(t)$ as

$$\frac{ds_z}{dt} = -\frac{L^2}{(L^2 + \Delta^2)\tau} s_z.$$
 (B2)

Its solution yields $s_z(t) = s_z(0)e^{-t/\tau_s}$ with

$$\frac{1}{\tau_{\rm s}} = \frac{L^2}{L^2 + \Delta^2} \frac{1}{\tau}.$$
 (B3)

In the limit of small SOC, $L \ll \Delta$, it returns the usual Elliott formula. However, it is interesting to note that Eq. (B3) also contains the solution when L is significant, a result which was derived in Ref. [35].

To obtain the result in the GEY regime, we consider the dynamics of an individual pseudospin according to

$$\frac{ds}{dt} = -s \times \mathbf{\Omega}_k,\tag{B4}$$

where the minus sign is due to the negative electron charge and Ω_k 's are given in Eq. (13). The pseudospins precess by only a small angle between two consecutive momentum scatterings due to the short τ since $(L, \Delta) \ll \Gamma$. Thus Eq. (B4) can be linearized and the change in the s_z component during a short time τ for a state A reads (the result is obtained for a B state in a similar manner)

$$\Delta s = -\frac{2\tau}{\hbar} \begin{bmatrix} -s_y \Delta/2 - s_z \text{Im}[L_k] \\ -s_z \text{Re}[L_k] - s_x \Delta/2 \\ s_x \text{Im}[L_k] + s_y \text{Re}[L_k] \end{bmatrix}.$$
 (B5)

Equation (B5) means that the change in the z component is unaffected by the Δ term, i.e., the time evolution of the z component behaves as if only the SOC related fields were present.

Then, the DP theory can be applied with the result in Eq. (2) with the $\mathcal L$ substituted by L, which leads to the generalized EY result in the $\Delta \ll \Gamma$ limit as

$$\Gamma_{\rm s} = \frac{L^2}{\Gamma}.\tag{B6}$$

APPENDIX C: MONTE CARLO RESULTS OF THE SPIN-RELAXATION RATE FOR THE EY MODEL WITH ISOTROPIC SOC

The main text described that spin-relaxation time in MgB_2 can be quantitatively reproduced using our approach. The assumptions of the calculation are the presence of a single (i.e., k-independent) band-band separation value (Δ) and an isotropic four-band EY model (two kinetic bands). Isotropy means that its Hamiltonian is invariant to spatial rotations. These are quite significant simplifying assumptions, however the agreement between the calculation and the experimental data proves that this model is indeed adequate.

In this isotropic case, it is sufficient to specify the Hamiltonian for a single k_0 point on the spherical Fermi surface. The matrix elements are obtained for an arbitrary point by transforming this Hamiltonian by means of rotations. For convenience we specify this given k_0 wave vector as the "north pole" on the Fermi sphere $[k_0 = (0,0,k_{\rm F})]$. We are interested in the matrix elements of the Hamiltonian such as

$$H_{\alpha,\sigma;\alpha',\sigma'}(\mathbf{k}) = \langle \mathbf{k}, \alpha, \sigma | H | \mathbf{k}, \alpha', \sigma' \rangle, \tag{C1}$$

where α and σ are the band and spin indices, respectively.

The matrix elements between wave functions with different k and k' are zero. Treating the α, σ pair as a single index, the Hamiltonian can be conveniently treated as a k dependent 4×4 matrix. For the case of a retained inversion symmetry, the most general form of this matrix reads

$$\mathbf{H} = \begin{bmatrix} 1 \uparrow & 1 \downarrow & 2 \uparrow & 2 \downarrow \\ 1 \uparrow & 0 & 0 & L_{2,k} & L_{1,k} \\ 0 & 0 & L_{1,k}^* & -L_{2,k} \\ L_{2,k} & L_{1,k} & \Delta_k & 0 \\ L_{1,k}^* & -L_{2,k} & 0 & \Delta_k \end{bmatrix}.$$
(C2)

Rotations around the z axis leave the k_0 vector invariant. The generator of rotations around the z is $J_z = L_z + S_z$:

$$[H, J_z] = 0,$$

$$\langle \mathbf{k}_0, \alpha, \sigma | [H, J_z] | \mathbf{k}_0, \alpha', \sigma' \rangle = 0.$$
(C3)

Since we have two nondegenerate kinetic bands, we can assume that the angular momentum is quenched. It yields

$$\langle \mathbf{k}_0, \alpha, \sigma | [H, S_z] | \mathbf{k}_0, \alpha', \sigma' \rangle = 0,$$

$$[H, S_z]_{\alpha, \sigma; \alpha', \sigma'}(\mathbf{k}_0) = \begin{bmatrix} 0 & 0 & 0 & -L_{1, \mathbf{k}_0} \\ 0 & 0 & L_{1, \mathbf{k}_0}^* & 0 \\ 0 & -L_{1, \mathbf{k}_0} & 0 & 0 \\ L_{1, \mathbf{k}_0}^* & 0 & 0 & 0 \end{bmatrix},$$

$$L_{1, \mathbf{k}_0} = 0. \tag{C4}$$

This means that for the k_0 point the SOC matrix elements are described by a single real parameter: $L = L_{2,k_0}$.

A general rotation transformation is described by the following operation:

$$R = e^{-iJa\varphi/\hbar} = e^{-iLa\varphi/\hbar}e^{-iSa\varphi/\hbar},$$
 (C5)

where a and φ denote the axis and angle of the rotation, respectively. Clearly, the rotation operation acts separately on the kinetic and spin parts of the wave function, i.e.,

$$R|\mathbf{k},\alpha,\sigma\rangle = (e^{-i\mathbf{L}\mathbf{a}\varphi/\hbar}|\mathbf{k},\alpha\rangle) \otimes (e^{-i\mathbf{S}\mathbf{a}\varphi/\hbar}|\sigma\rangle).$$
 (C6)

For any $k \neq k_0$, we can define a single operation that rotates k_0 to k:

$$a_{k_0,k} = \frac{k_0 \times k}{|k_0 \times k|},$$

$$\varphi_{k_0,k} = \sin^{-1}(|k_0 \times k|),$$

$$R_{k_0,k} = e^{-iJa_{k_0,k}\varphi_{k_0,k}/\hbar}.$$
(C7)

The spatial rotations are symmetries of the kinetic part of the Hamiltonian, thus the rotation does not mix wave functions from different bands, i.e.,

$$|\mathbf{k}, \alpha\rangle = R_{\mathbf{k}_0, \mathbf{k}} |\mathbf{k}_0, \alpha\rangle.$$
 (C8)

Our Hamiltonian is symmetric to these rotations, therefore

$$[H, R_{k_0,k}] = 0, \quad H = R_{k_0,k} H R_{k_0,k}^{-1}.$$
 (C9)

The only nonzero matrix elements in the k vector read

$$\langle \boldsymbol{k}, \alpha, \sigma | H | \boldsymbol{k}, \alpha', \sigma' \rangle = \langle \boldsymbol{k}, \alpha, \sigma | R_{k_0, k} H R_{k_0, k}^{-1} | \boldsymbol{k}, \alpha', \sigma' \rangle,$$

$$\langle \boldsymbol{k}, \alpha, \sigma | H | \boldsymbol{k}, \alpha', \sigma' \rangle$$

$$= \langle \boldsymbol{k}_0, \alpha, \sigma | e^{-iSa_{k_0, k}\varphi_{k_0, k}/\hbar} H e^{iSa_{k_0, k}\varphi_{k_0, k}/\hbar} | \boldsymbol{k}_0, \alpha', \sigma' \rangle,$$

$$H_{\alpha, \sigma; \alpha', \sigma'}(\boldsymbol{k})$$

$$= \sum_{n=1}^{\infty} [e^{-iSa\varphi/\hbar}]_{\sigma, \sigma_1} H_{\alpha, \sigma_1; \alpha', \sigma_2}(\boldsymbol{k}_0) [e^{iSa\varphi/\hbar}]_{\sigma_2, \sigma'}. \quad (C10)$$

The spin rotation can be calculated using a matrix exponential of 2×2 matrices. This allows us to arrive at the final SOC values at the $\mathbf{k} = (k_x, k_y, k_z)$ point:

$$L_{1,k} = \frac{-Lk_x - iLk_y}{k_F},$$

$$L_{2,k} = \frac{Lk_z}{k_F}.$$
(C11)

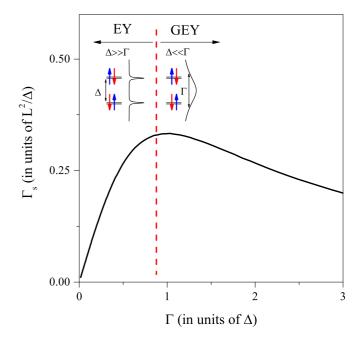


FIG. 5. Spin-relaxation rate Γ_s calculated for isotropic SOC with varying momentum relaxation rate Γ . The schematics of the band structure is also shown and the EY and GEY regimes are indicated. Note that the crossover between the two regimes is rather smooth.

This remarkably simple and symmetric result allows the calculation of the SOC Hamiltonian for any k points. This, together with the above transformation of the EY Hamiltonian to the DP problem and the corresponding Monte Carlo method described in the main text, allows the calculation of spin-relaxation times for this isotropic system.

Figure 5 shows the universal curve which is obtained for the spin relaxation of a metal with inversion symmetry and isotropic SOC. The details of the calculation are outlined in the main text and essentially mimic the method in Ref. [31]. The curve is well fitted by

$$\Gamma_{\rm s}(\Gamma) = \frac{2}{3} \frac{\Gamma}{1 + \Gamma^2},\tag{C12}$$

where Γ_s is measured in units of L^2/Δ and Γ is measured in units of Δ . The 2/3 prefactor depends on the way the SOC matrix elements are defined and the original Elliott result allows for the presence of similar factors (usually denoted by α).

^[1] S. A. Wolf, D. D. Awschalom, R. A. Buhrman, J. M. Daughton, S. von Molnár, M. L. Roukes, A. Y. Chtchelkanova, and D. M. Treger, Science 294, 1488 (2001).

^[2] I. Žutić, J. Fabian, and S. Das Sarma, Rev. Mod. Phys. 76, 323 (2004).

^[3] M. W. Wu, J. H. Jiang, and M. Q. Weng, Phys. Rep. 493, 61 (2010).

^[4] R. J. Elliott, Phys. Rev. 96, 266 (1954).

^[5] Y. Yafet, Solid State Phys. 14, 1 (1963).

^[6] M. I. Dyakonov and V. I. Perel, Sov. Phys. Solid State, USSR 13, 3023 (1972).

^[7] G. E. Pikus and A. N. Titkov, in *Spin Relaxation under Optical Orientation in Semiconductors* (Elsevier, Amsterdam, 1984), pp. 73–131.

^[8] N. Tombros, C. Józsa, M. Popinciuc, H. T. Jonkman, and B. J. van Wees, Nature (London) **448**, 571 (2007).

^[9] T.-Y. Yang, J. Balakrishnan, F. Volmer, A. Avsar, M. Jaiswal, J. Samm, S. R. Ali, A. Pachoud, M. Zeng, M. Popinciuc *et al.*, Phys. Rev. Lett. **107**, 047206 (2011).

^[10] W. Han, K. Pi, K. M. McCreary, Y. Li, J. J. I. Wong, A. G. Swartz, and R. K. Kawakami, Phys. Rev. Lett. 105, 167202 (2010).

- [11] W. Han and R. K. Kawakami, Phys. Rev. Lett. 107, 047207 (2011).
- [12] Y. Yafet, Phys. Lett. A 98, 287 (1983).
- [13] J. S. Helman and F. Beuneu, Phys. Rev. B 30, 2487 (1984).
- [14] J. Fabian and S. Das Sarma, Phys. Rev. Lett. 81, 5624 (1998).
- [15] J. Fabian and S. Das Sarma, Phys. Rev. Lett. 83, 1211 (1999).
- [16] F. Simon, A. Jánossy, T. Fehér, F. Murányi, S. Garaj, L. Forró, C. Petrovic, S. L. Bud'ko, G. Lapertot, V. G. Kogan, and P. C. Canfield, Phys. Rev. Lett. 87, 047002 (2001).
- [17] A. Jánossy, O. Chauvet, S. Pekker, J. R. Cooper, and L. Forró, Phys. Rev. Lett. 71, 1091 (1993).
- [18] F. Simon, B. Dóra, F. Murányi, A. Jánossy, S. Garaj, L. Forró, S. Bud'ko, C. Petrovic, and P. C. Canfield, Phys. Rev. Lett. 101, 177003 (2008).
- [19] B. Dóra and F. Simon, Phys. Rev. Lett. 102, 137001 (2009).
- [20] A. A. Burkov and L. Balents, Phys. Rev. B 69, 245312 (2004).
- [21] W. Knap, C. Skierbiszewski, A. Zduniak, E. Litwin-Staszewska, D. Bertho, F. Kobbi, J. L. Robert, G. E. Pikus, F. G. Pikus, S. V. Iordanskii *et al.*, Phys. Rev. B **53**, 3912 (1996).
- [22] N. S. Averkiev and L. E. Golub, Phys. Rev. B 60, 15582 (1999).
- [23] V. N. Gridnev, J. Exp. Theor. Phys. Lett. 74, 380 (2001).

- [24] M. Krauß, M. Aeschlimann, and H. C. Schneider, Phys. Rev. Lett. 100, 256601 (2008).
- [25] M. A. Brand, A. Malinowski, O. Z. Karimov, P. A. Marsden, R. T. Harley, A. J. Shields, D. Sanvitto, D. A. Ritchie, and M. Y. Simmons, Phys. Rev. Lett. 89, 236601 (2002).
- [26] W. J. H. Leyland, R. T. Harley, M. Henini, A. J. Shields, I. Farrer, and D. A. Ritchie, Phys. Rev. B 76, 195305 (2007).
- [27] M. Cosacchi, M. Cygorek, F. Ungar, and V. M. Axt, Phys. Rev. B 95, 195313 (2017).
- [28] P. Boross, B. Dóra, A. Kiss, and F. Simon, Sci. Rep. 3, 3233 (2013).
- [29] D. Culcer and R. Winkler, Phys. Rev. B 76, 195204 (2007).
- [30] R. Winkler, D. Culcer, S. J. Papadakis, B. Habib, and M. Shayegan, Semicond. Sci. Technol. 23, 114017 (2008).
- [31] L. Szolnoki, A. Kiss, B. Dóra, and F. Simon, Sci. Rep. 7, 9949 (2017).
- [32] J. Fabian, A. Matos-Abiague, C. Ertler, P. Stano, and I. Zutic, Acta Physica Slovaca 57, 565 (2007).
- [33] M. W. Wu and C. Z. Ning, Eur. Phys. J. B 18, 373 (2000).
- [34] M. W. Wu and C. Z. Ning, Phys. Status Solidi B 222, 523 (2000).
- [35] A. Kiss, L. Szolnoki, and F. Simon, Sci. Rep. 6, 22706 (2016).